Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.625 inches
Overall Diameter:
0.675 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-228
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
500.0 reverse voltage, dc
Current Rating Per Characteristic:
30.00 amperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Precious Material And Location:
External surfaces gold
Precious Material:
Gold
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0